NPN Triple Diffused Planar Silicon Transistor

2SC4630



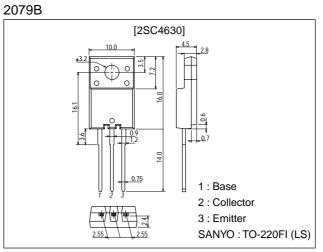
900V/100mA High-Voltage Amplifier, High-Voltage Switching Applications

### Features

- $\cdot$  High breakdown voltage (V<sub>CEO</sub> min=900V).
- · Small Cob (typical Cob=2.8pF).
- · Full isolation package.
- $\cdot$  High reliability (Adoption of HVP process).

## Package Dimensions

unit:mm



# **Specifications**

#### Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CBO</sub>		1500	V
Collector-to-Emitter Voltage	VCEO		900	V
Emitter-to-Base Voltage	VEBO		5	V
Collector Current	IC		100	mA
Collector Current (Pulse)	ICP		300	mA
Collector Dissipation	PC		2	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

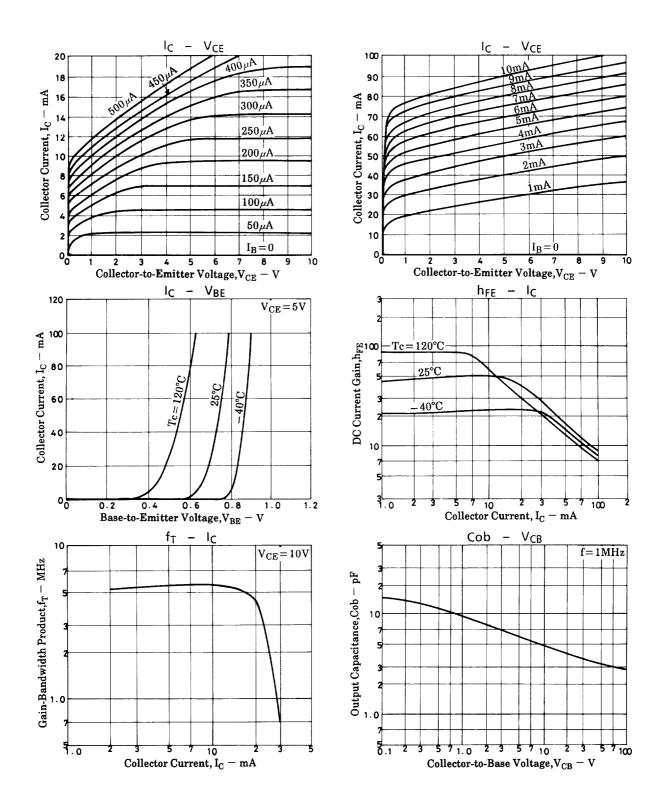
### **Electrical Characteristics at Ta = 25°C**

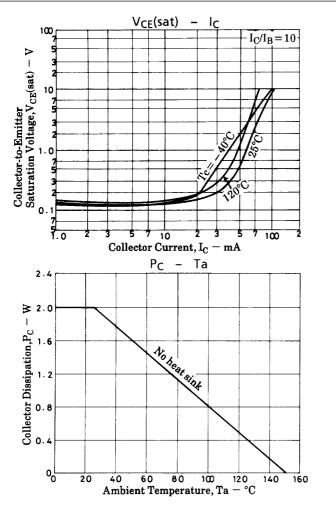
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	ICBO	V <sub>CB</sub> =900V, I <sub>E</sub> =0			10	μΑ
Emitter Cutoff Current	IEBO	V <sub>EB</sub> =4V, I <sub>C</sub> =0			10	μΑ
DC Current Gain	h <sub>FE</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =10mA	30			
Gain-Bandwidth Product	fT	V <sub>CE</sub> =10V, I <sub>C</sub> =10mA		6		MHz
Collector-to-Emitter Saturation Voltage	VCE(sat)	I <sub>C</sub> =20mA, I <sub>B</sub> =4mA			5	V
Base-to-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =20mA, I <sub>B</sub> =4mA			2	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I <sub>C</sub> =1mA, I <sub>E</sub> =0	1500			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I <sub>C</sub> =1mA, R <sub>BE</sub> =∞	900			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I <sub>E</sub> =1mA, I <sub>C</sub> =0	5			V

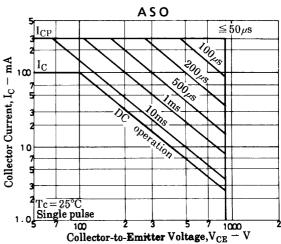
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Output Capacitance	Cob	V <sub>CB</sub> =100V, f=1MHz		2.8		pF
Thermal Resistance	Rthj-c	Junction – case			12.5	°C/W







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